



JIANGSU CHANGJIANG ELECTRONICS TECHNOLOGY CO., LTD

## SOT-89-3L Plastic-Encapsulate Transistors

### 2SA1797 TRANSISTOR (PNP)

#### FEATURES

- Low saturation voltage
- Excellent DC current gain characteristics
- Complements to 2SC4672

#### MAXIMUM RATINGS ( $T_a=25^\circ\text{C}$ unless otherwise noted)

Symbol	Parameter	Value	Unit
$V_{\text{CBO}}$	Collector-Base Voltage	-50	V
$V_{\text{CEO}}$	Collector-Emitter Voltage	-50	V
$V_{\text{EBO}}$	Emitter-Base Voltage	-6	V
$I_C$	Continuous Collector Current	-2	A
$I_{\text{CM}}$	Peak Pluse Current	-3	A
$P_C$	Collector Power dissipation	500	mW
$T_J$	Junction Temperature	150	$^\circ\text{C}$
$T_{\text{stg}}$	Storage Temperature	-55~150	$^\circ\text{C}$

#### ELECTRICAL CHARACTERISTICS ( $T_a=25^\circ\text{C}$ unless otherwise specified)

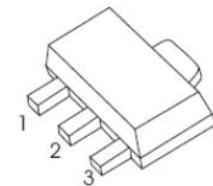
Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	$V_{(\text{BR})\text{CBO}}$	$I_C=-50\mu\text{A}, I_E=0$	-50			V
Collector-emitter breakdown voltage	$V_{(\text{BR})\text{CEO}}$	$I_C=-1\text{mA}, I_B=0$	-50			V
Emitter-base breakdown voltage	$V_{(\text{BR})\text{EBO}}$	$I_E=-50\mu\text{A}, I_C=0$	-6			V
Collector cut-off current	$I_{\text{CBO}}$	$V_{\text{CB}}=-50\text{V}, I_E=0$			-0.1	$\mu\text{A}$
Emitter cut-off current	$I_{\text{EBO}}$	$V_{\text{EB}}=-5\text{V}, I_C=0$			-0.1	$\mu\text{A}$
DC current gain	$h_{\text{FE}}$	$V_{\text{CE}}=-2\text{V}, I_C=-500\text{mA}$	82		270	
Collector-emitter saturation voltage	$V_{\text{CE}(\text{sat})}$	$I_C=-1\text{A}, I_B=-50\text{mA}$			-0.35	V
Transition frequency	$f_T$	$V_{\text{CE}}=-2\text{V}, I_C=-0.5\text{A}, f=100\text{MHz}$		200		MHz
Collector output capacitance	$C_{\text{ob}}$	$V_{\text{CB}}=-10\text{V}, I_E=0, f=1\text{MHz}$		36		pF

#### CLASSIFICATION OF $h_{\text{FE}}$

Rank	P	Q
Range	82-180	120-270
Marking	AGP	AGQ

#### SOT-89-3L

##### 1. BASE

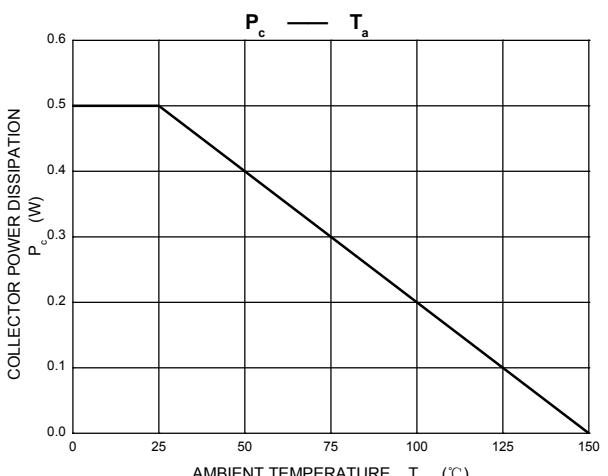
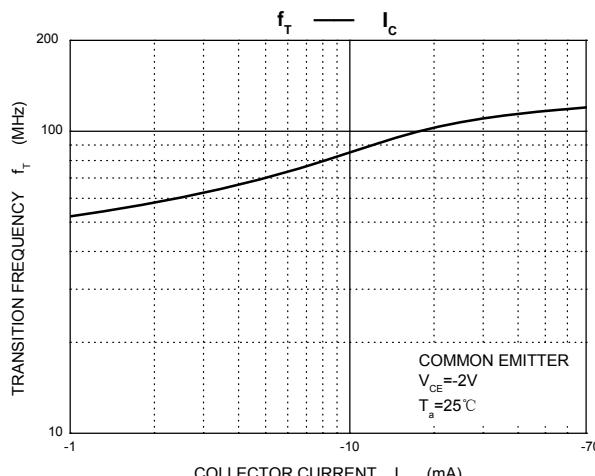
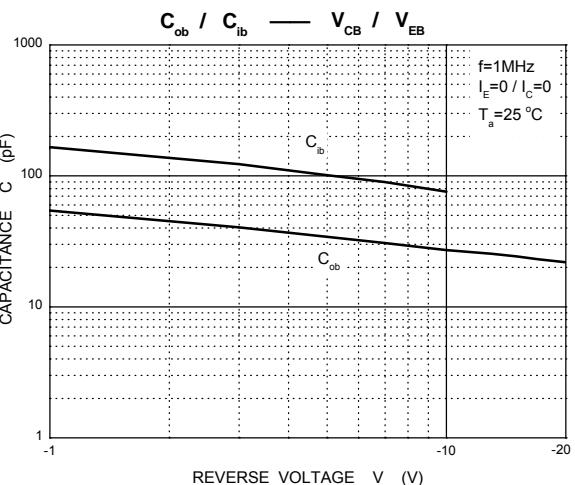
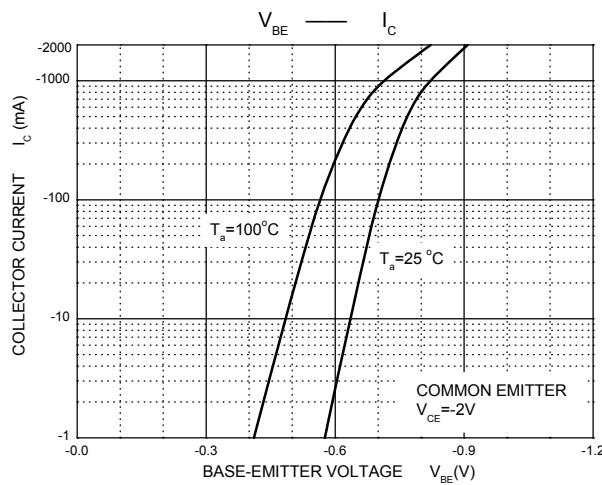
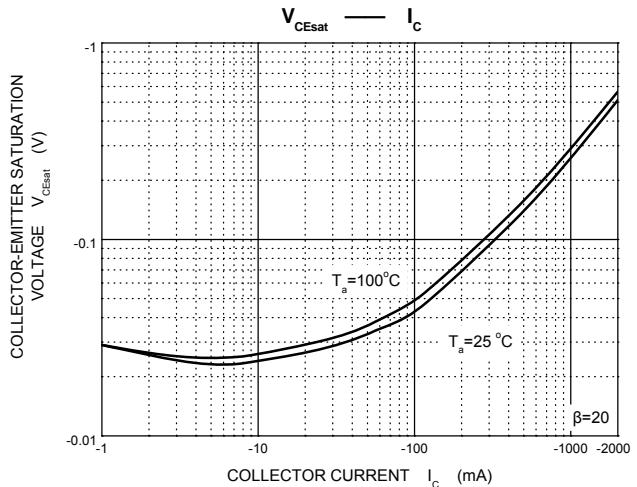
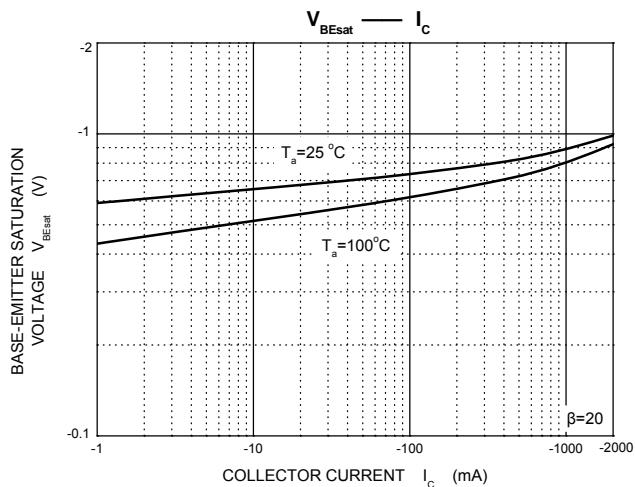
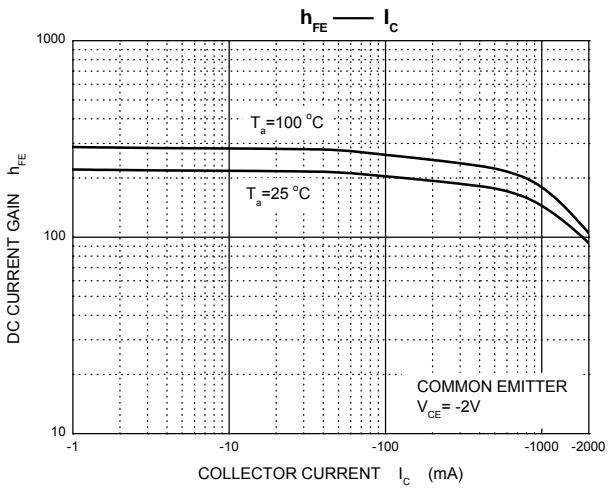
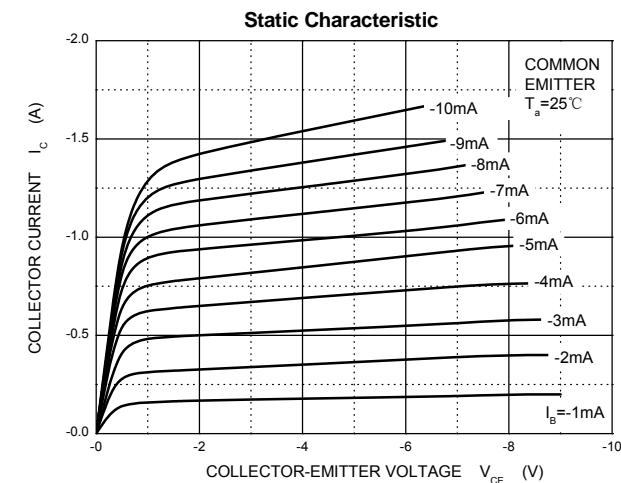


##### 2. COLLECTOR

##### 3. Emitter

# Typical Characteristics

2SA1797



# X-ON Electronics

Largest Supplier of Electrical and Electronic Components

***Click to view similar products for Bipolar Transistors - BJT category:***

***Click to view products by Changjiang manufacturer:***

Other Similar products are found below :

[619691C](#) [MCH4017-TL-H](#) [MMBT-2369-TR](#) [BC546/116](#) [BC557/116](#) [BSW67A](#) [NJVMJD148T4G](#) [NTE123AP-10](#) [NTE153MCP](#) [NTE16](#)  
[NTE195A](#) [NTE92](#) [C4460](#) [2N4401-A](#) [2N6728](#) [2SA1419T-TD-H](#) [2SA2126-E](#) [2SB1204S-TL-E](#) [2SC2712S-GR,LF](#) [2SC5488A-TL-H](#)  
[2SD2150T100R](#) [SP000011176](#) [2N2907A](#) [2N3904-NS](#) [2N5769](#) [2SC2412KT146S](#) [2SD1816S-TL-E](#) [CPH6501-TL-E](#) [MCH4021-TL-E](#)  
[MJE340](#) [US6T6TR](#) [NJK0281DG](#) [732314D](#) [CPH3121-TL-E](#) [CPH6021-TL-H](#) [873787E](#) [IMZ2AT108](#) [UMX21NTR](#) [MCH6102-TL-E](#)  
[NJK0302DG](#) [2N3583](#) [30A02MH-TL-E](#) [NSV40301MZ4T1G](#) [NTE13](#) [NTE26](#) [NTE282](#) [NTE323](#) [NTE350](#) [NTE81](#) [STX83003-AP](#)